NSN 5962-01-087-8528

Memory Microcircuit - Page 1 of 1



view Online at https://aerobasegroup.com/nsn/5962-01-067-6526
Body Length:
Between 0.850 inches and 0.930 inches
Body Width:
Between 0.240 inches and 0.295 inches
Body Height:
Between 0.165 inches and 0.200 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and bipolar and programmable and programmed and w/enable and w/buffered
output and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Terminal Surface Treatment:
Tin
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
09344-34803 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Fiig: A458a0

Yes - demil/mli